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Attorney Docket: 081468

IN THE CLAIMS:



This listing of claims will replace all prior versions, and listings, of claims in the application:

- 1. (Original) A device manufacturing method comprising the steps of:
- (a) providing a polished silicon substrate having a background portion and one or more target portions, said background and target portions having Si-H bonds on the surface;
- (b) irradiating said one or more target portions using a patterned beam of radiation and in the presence of oxygen to provide a layer of silicon oxide on said target portion(s);
- (c) reacting at least a part of said background portion with a first composition comprising one or more compounds selected from 1-alkenes and 1-alkynes;
 - (d) removing said layer of silicon oxide from said target portion(s);
- (e) reacting one or more target portions with a further composition comprising one or more compounds selected from 1-alkenes and 1-alkynes, to covalently attach said one or more compounds to said target portion(s).
- 2. (Original) A method according to claim 1, wherein step (e) comprises irradiating said one or more target portions in the presence of the further composition, using a patterned beam of radiation.
- 3. (Currently Amended) A method according to claim 1 or 2, which method further comprises repeating step (e) one or more times, each repetition being carried out at one or more different target portions and in the presence of a further composition comprising one or more compounds selected from 1-alkenes and 1-alkynes, each further composition being the same or different.
 - 4. (Original) A device manufacturing method comprising the steps of:
- (a1) providing a polished silicon substrate having a background portion and one or more target portions, said background and target portions having Si-H bonds on the surface;

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(b1) reacting one or more target portions with a further composition comprising one or more compounds selected from 1-alkenes and 1-alkynes, to covalently attach said one or more compounds to said target portion(s); and

- (c1) reacting at least a part of said background portion with a first composition comprising one or more compounds selected from 1-alkenes and 1- alkynes.
- 5. (Original) A method according to claim 4, wherein step (b1) comprises irradiating said one or more target portions in the presence of the further composition, using a patterned beam of radiation.
- 6. (Currently Amended) A method according to claim 4 or 5, which method further comprises repeating step (b1) one or more times, each repetition being carried out at one or more different target portions and in the presence of a further composition comprising one or more compounds selected from 1-alkenes and 1-alkynes, each further composition being the same or different.
- 7. (Currently Amended) A method according to <u>claim 1</u> any one of the preceding elaims, wherein one or more of the target portions has in its surface a part of a transistor structure.
- 8. (Original) A method according to claim 7, wherein said silicon substrate comprises 10 or more target portions, each having a part of a transistor structure in its surface.
- 9. (Currently Amended) A method according to <u>claim 1</u> any one of the preceding elaims, wherein said first composition comprises one or more compounds of formula (I) or (IA):

$$(CH_2)_n - X - (CH_2)_m - R'$$
 (I)

$$=$$
 (CH₂)_n-X-(CH₂)_m-R' (IA)

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wherein n and m independently represent an integer of from 1 to 36; X represents a single bond,-O-,-S-,-C(O)-O-,-O-C(O)- or an unsubstituted C2-C4 alkenylene or alkynylene group containing one or two double and/or triple bonds; and R/ represents hydrogen.

10. (Currently Amended) A method according to <u>claim 1</u> any one of the preceding elaims, wherein the further composition comprises one or more compounds of formula (II) or (IIA):

$$(CH_2)_n - X' - (CH_2)_m - R''$$
 (II)

$$=$$
 (CH₂)_n-X'-(CH₂)_m-R" (IIA)

wherein n and m independently represent an integer of from 1 to 36; X' represents a singlebond,-O-,-S-,-C(O)-O-,-O-C(O)- or an unsubstituted C2-C4 alkenylene or alkynylene group containing one or two double and/or triple bonds; R// represents hydrogen or a group selected from halogens, cyanide groups, carboxylic acid derivatives including esters and amides, alkoxy groups, thio groups, amines, including mono-and di-alkylamines, hydroxy groups and receptor derivatives which are capable of interacting with a chemical or biological substance.

- 11. (Original) A method according to claim 10, wherein R// represents an oligosaccharide or an oligopeptide which is capable of interacting with a chemical or biological substance.
- 12. (Original) A method according to claim 11, wherein said further composition comprises a compound of formula (IIIA) or(IIIB):

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which is optionally protected on the saccharide units with protecting groups, wherein n, m and X^{\prime} are as defined in claim 10.

- 13. (Currently Amended) A device obtained or obtainable by the method of claim 1 any one of the preceding claims.
 - 14. (Original) A device comprising:
- a polished silicon substrate having a background portion and one or more target portions, at least one of said target portions having a part of a transistor structure in its surface;
- an organic monolayer which is directly coupled to at least a part of the surface of the silicon substrate by covalent bonds, said organic monolayer comprising receptor compounds, each of which is capable of interacting with a chemical or biological substance, in area(s) which cover the or each target portion having a part of a transistor structure;

wherein the part of a transistor structure combined with the organic monolayer containing receptor compounds forms a field effect transistor.

- 15. (Original) A device according to claim 14, wherein said silicon substrate has 2 or more, preferably 10 or more, target portions.
- 16. (Original) A device according to claim 15, wherein the monolayer comprises receptor compounds of a first type in an area covering a first target portion, and receptor compounds of a different type in an area covering a second target portion.

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- 17. (Currently Amended) A device according to <u>claim 14</u> any one of claims 14 to 16, wherein the monolayer in the area covering at least one target portion comprises one or more oligosaccharide or oligopeptide derivatives.
- 18. (Original) A device according to claim 17, wherein the monolayer in the area covering at least one target portion comprises an oligosaccharide derivative of formula (III)

wherein n, m and X' are as defined in claim 10.

- 19. (Currently Amended) Use of a device according to <u>claim 13</u> any one of claims 13 to 18 as a sensor.
- 20. (Original) A method of coupling an oligosaccharide or oligopeptide derivative to a polished silicon surface, which method comprises reacting a compound of formula (VI) or (VIA):

Oligo—O—
$$(CH_2)_m - X'$$
— $(CH_2)_n$ — $CH = CH_2$ (VI)

Oligo—
$$O$$
— $(CH_2)_m$ — X' — $(CH_2)_n$ — $CH \equiv CH_2$ (VIA)

wherein Oligo represents an oligosaccharide or oligopeptide derivative and n, m and X' are as defined in claim 10, with a silicon substrate having Si-H bonds at its surface, substantially in the absence of oxygen and in the presence of heat or UV or visible radiation.